



STQ1NK80ZR-AP - STN1NK80Z STD1NK80Z - STD1NK80Z-1

N-CHANNEL 800V - 13 Ω - 1 A TO-92 /SOT-223/DPAK/IPAK
Zener - Protected SuperMESH™ MOSFET

Table 1: General Features

TYPE	V _{DSS}	R _{DS(on)}	I _D	P _w
STQ1NK80ZR-AP	800 V	< 16 Ω	0.3 A	3 W
STN1NK80Z	800 V	< 16 Ω	0.25A	2.5 W
STD1NK80Z	800 V	< 16 Ω	1.0 A	45 W
STD1NK80Z-1	800 V	< 16 Ω	1.0 A	45 W

- TYPICAL R_{DS(on)} = 13Ω
- EXTREMELY HIGH dv/dt CAPABILITY
- ESD IMPROVED CAPABILITY
- 100% AVALANCHE TESTED
- NEW HIGH VOLTAGE BENCHMARK
- GATE CHARGE MINIMIZED

DESCRIPTION

The SuperMESH™ series is obtained through an extreme optimization of ST's well established strip-based PowerMESH™ layout. In addition to pushing on-resistance significantly down, special care is taken to ensure a very good dv/dt capability for the most demanding applications. Such series complements ST full range of high voltage MOSFETs including revolutionary MDmesh™ products.

APPLICATIONS

- AC ADAPTORS AND BATTERY CHARGERS
- SWITCH MODE POWER SUPPLIES (SMPS)

Figure 1: Package

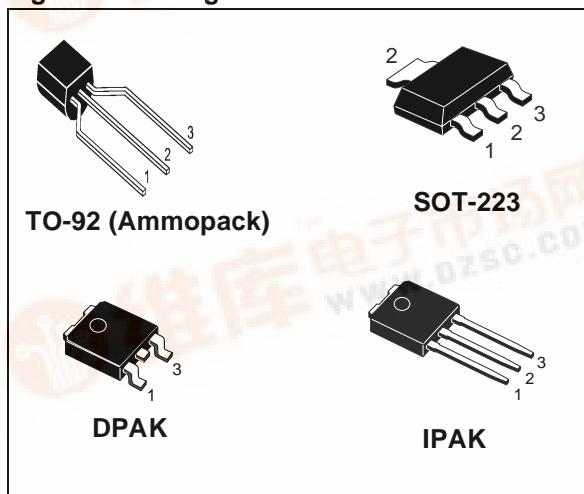


Figure 2: Internal Schematic Diagram

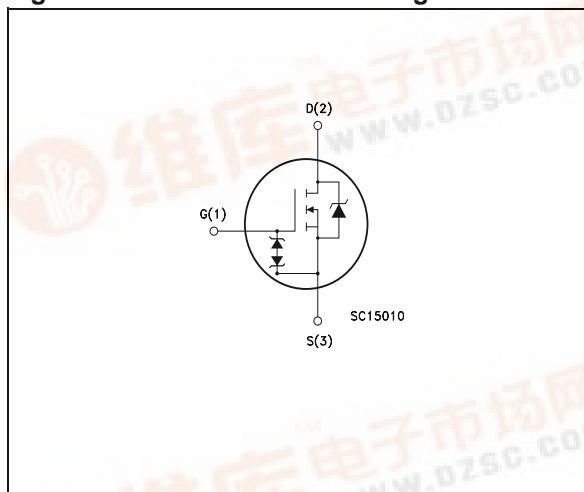


Table 2: Order Codes

SALES TYPE	MARKING	PACKAGE	PACKAGING
STQ1NK80ZR-AP	Q1NK80ZR	TO-92	AMMOPAK
STN1NK80Z	N1NK80Z	SOT-223	TAPE & REEL
STD1NK80ZT4	D1NK80Z	DPAK	TAPE & REEL
STD1NK80Z-1	D1NK80Z	IPAK	TUBE

STQ1NK80ZR-AP - STN1NK80Z - STD1NK80Z - STD1NK80Z-1

Table 3: Absolute Maximum ratings

Symbol	Parameter	Value			Unit	
		TO-92	SOT-223	DPAK/IPAK		
V_{DS}	Drain-source Voltage ($V_{GS} = 0$)	800		V		
V_{DGR}	Drain-gate Voltage ($R_{GS} = 20 \text{ k}\Omega$)	800		V		
V_{GS}	Gate- source Voltage	± 30		V		
I_D	Drain Current (continuous) at $T_C = 25^\circ\text{C}$	0.3	0.25	1.0	A	
I_D	Drain Current (continuous) at $T_C = 100^\circ\text{C}$	0.19	0.16	0.63	A	
$I_{DM} (\bullet)$	Drain Current (pulsed)	5		A		
P_{TOT}	Total Dissipation at $T_C = 25^\circ\text{C}$	3	2	45	W	
	Derating Factor	0.025	0.02	0.36	W / $^\circ\text{C}$	
$V_{ESD(G-S)}$	Gate source ESD (HBM-C= 100pF, R= 1.5K Ω)	1000		V		
dv/dt (1)	Peak Diode Recovery voltage slope	4.5		V/ns		
T_j T_{stg}	Operating Junction Temperature Storage Temperature	-55 to 150		$^\circ\text{C}$		

(•) Pulse width limited by safe operating area

(1) $I_{SD} \leq 1 \text{ A}$, $dI/dt \leq 200 \text{ A}/\mu\text{s}$, $V_{DD} \leq 640$

Table 4: Thermal Data

		TO-92	SOT-223	DPAK/IPAK	Unit
$R_{thj-case}$	Thermal Resistance Junction-case Max	--	--	2.78	$^\circ\text{C}/\text{W}$
$R_{thj-amb(\#)}$	Thermal Resistance Junction-ambient Max	120	50	100	$^\circ\text{C}/\text{W}$
$R_{thj-lead}$	Thermal Resistance Junction-lead Max	40	--	--	$^\circ\text{C}/\text{W}$
T_I	Maximum Lead Temperature For Soldering Purpose	260	--	300	$^\circ\text{C}$

(#) When mounted on 1inch² FR-4 BOARD, 2 oz Cu

Table 5: Avalanche Characteristics

Symbol	Parameter	Max Value	Unit
I_{AR}	Avalanche Current, Repetitive or Not-Repetitive (pulse width limited by T_j max)	1	A
E_{AS}	Single Pulse Avalanche Energy (starting $T_j = 25^\circ\text{C}$, $I_D = I_{AR}$, $V_{DD} = 50 \text{ V}$)	50	mJ

Table 6: GATE-SOURCE ZENER DIODE

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
BV_{GSO}	Gate-Source Breakdown Voltage	$I_{GS}=\pm 1\text{mA}$ (Open Drain)	30			V

PROTECTION FEATURES OF GATE-TO-SOURCE ZENER DIODES

The built-in back-to-back Zener diodes have specifically been designed to enhance not only the device's ESD capability, but also to make them safely absorb possible voltage transients that may occasionally be applied from gate to source. In this respect the Zener voltage is appropriate to achieve an efficient and cost-effective intervention to protect the device's integrity. These integrated Zener diodes thus avoid the usage of external components.

STQ1NK80ZR-AP - STN1NK80Z - STD1NK80Z - STD1NK80Z-1

ELECTRICAL CHARACTERISTICS ($T_{CASE} = 25^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED)

Table 7: On/Off

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_{(BR)DSS}$	Drain-source Breakdown Voltage	$I_D = 1 \text{ mA}, V_{GS} = 0$	800			V
I_{DSS}	Zero Gate Voltage Drain Current ($V_{GS} = 0$)	$V_{DS} = \text{Max Rating}$ $V_{DS} = \text{Max Rating}, T_C = 125^\circ\text{C}$			1 50	μA μA
I_{GSS}	Gate-body Leakage Current ($V_{DS} = 0$)	$V_{GS} = \pm 20\text{V}$			± 10	μA
$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 50 \mu\text{A}$	3	3.75	4.5	V
$R_{DS(on)}$	Static Drain-source On Resistance	$V_{GS} = 10\text{V}, I_D = 0.5 \text{ A}$		13	16	Ω

Table 8: Dynamic

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$g_{fs}(1)$	Forward Transconductance	$V_{DS} = 15 \text{ V}, I_D = 0.5 \text{ A}$		0.8		S
C_{iss} C_{oss} C_{rss}	Input Capacitance Output Capacitance Reverse Transfer Capacitance	$V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}, V_{GS} = 0$		160 26 6.7		pF pF pF
$C_{oss \text{ eq.}}(3)$	Equivalent Output Capacitance	$V_{GS} = 0\text{V}, V_{DS} = 0\text{V} \text{ to } 640\text{V}$		9.5		pF
$t_{d(on)}$ t_r $t_{d(off)}$ t_f	Turn-on Delay Time Rise Time Turn-off Delay Time Fall Time	$V_{DD} = 400 \text{ V}, I_D = 0.5 \text{ A}$ $R_G = 4.7\Omega$ $V_{GS} = 10 \text{ V}$ (see Figure 21)		8 30 22 55		ns ns ns ns
Q_g Q_{gs} Q_{gd}	Total Gate Charge Gate-Source Charge Gate-Drain Charge	$V_{DD} = 640\text{V}, I_D = 1.0 \text{ A},$ $V_{GS} = 10\text{V}$ (see Figure 24)		7.7 1.4 4.5		nC nC nC

Table 9: Source Drain Diode

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{SD} $I_{SDM}(2)$	Source-drain Current Source-drain Current (pulsed)				1.0 5	A A
$V_{SD}(1)$	Forward On Voltage	$I_{SD} = 1.0 \text{ A}, V_{GS} = 0$			1.6	V
t_{rr} Q_{rr} I_{RRM}	Reverse Recovery Time Reverse Recovery Charge Reverse Recovery Current	$I_{SD} = 1.0 \text{ A}, dI/dt = 100 \text{ A}/\mu\text{s}$ $V_{DD} = 50 \text{ V}, T_j = 25^\circ\text{C}$ (see Figure 22)		365 802 4.4		ns nC A
t_{rr} Q_{rr} I_{RRM}	Reverse Recovery Time Reverse Recovery Charge Reverse Recovery Current	$I_{SD} = 1.0 \text{ A}, dI/dt = 100 \text{ A}/\mu\text{s}$ $V_{DD} = 50 \text{ V}, T_j = 150^\circ\text{C}$ (see Figure 22)		388 802.7 4.6		ns nC A

Note: 1. Pulsed: Pulse duration = 300 μs , duty cycle 1.5 %.

2. Pulse width limited by safe operating area.

3. $C_{oss \text{ eq.}}$ is defined as a constant equivalent capacitance giving the same charging time as C_{oss} when V_{DS} increases from 0 to 80% V_{DSS}

STQ1NK80ZR-AP - STN1NK80Z - STD1NK80Z - STD1NK80Z-1

Figure 3: Safe Operating Area for SOT-223

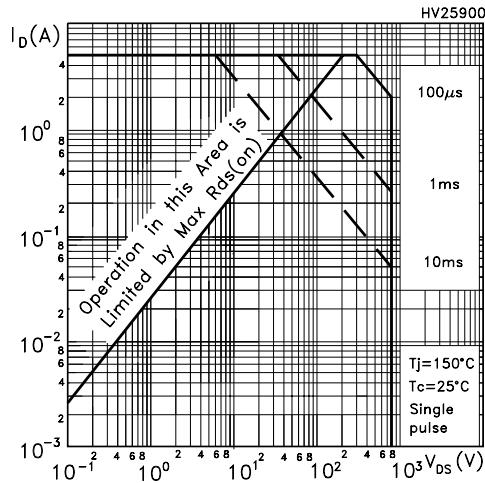


Figure 4: Safe Operating Area for TO-92

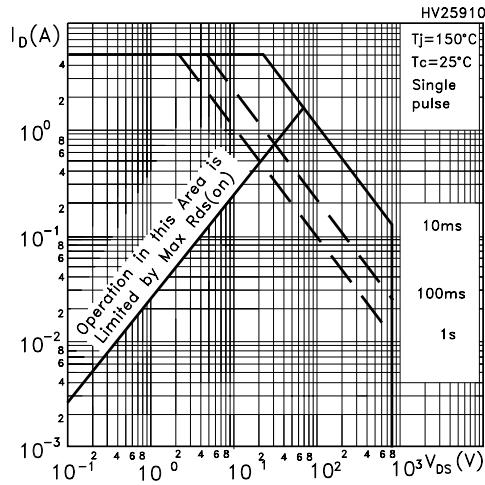


Figure 5: Safe Operating Area for IPAK-DPAK

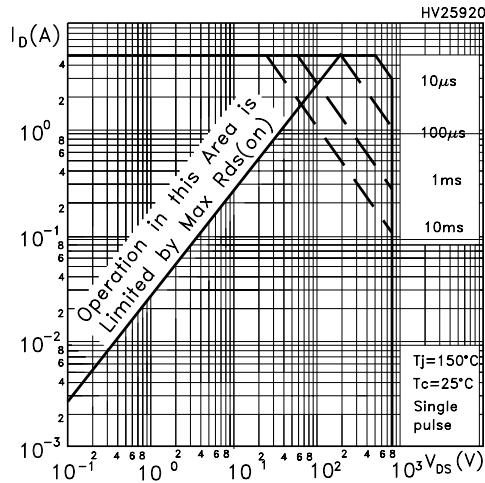


Figure 6: Thermal Impedance for SOT-223

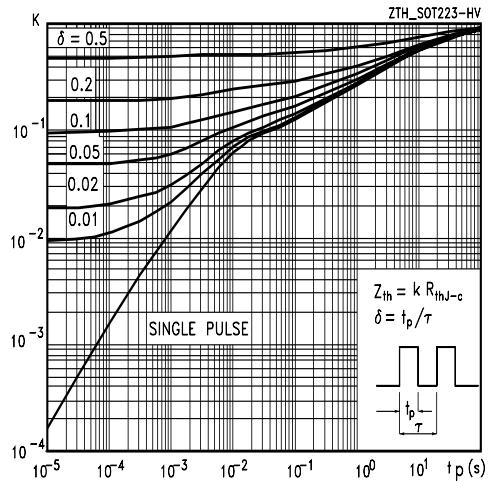


Figure 7: Thermal Impedance for TO-92

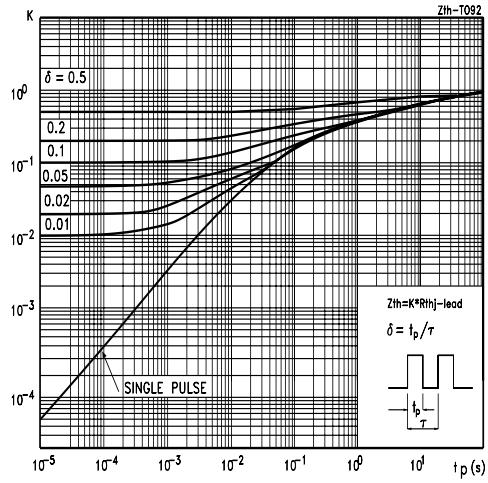
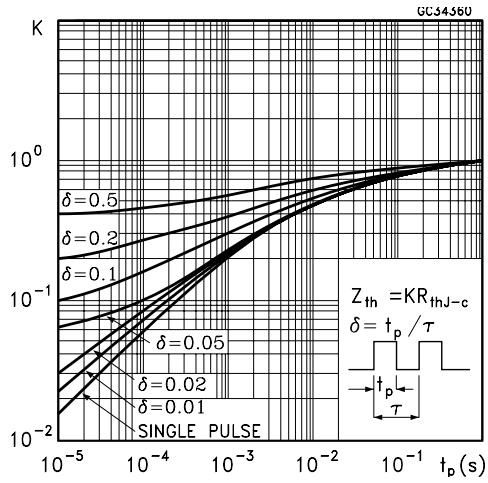


Figure 8: Thermal Impedance for DPAK-IPAK



STQ1NK80ZR-AP - STN1NK80Z - STD1NK80Z - STD1NK80Z-1

Figure 9: Output Characteristics

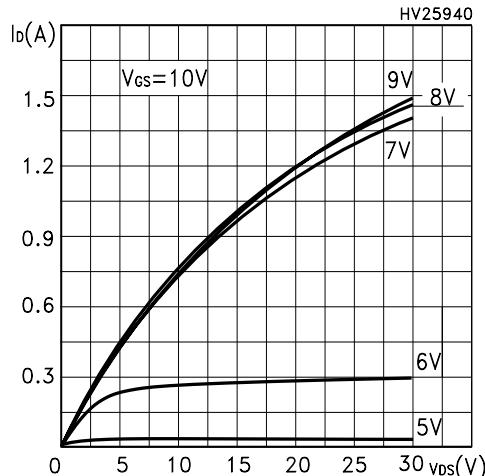


Figure 10: Transconductance

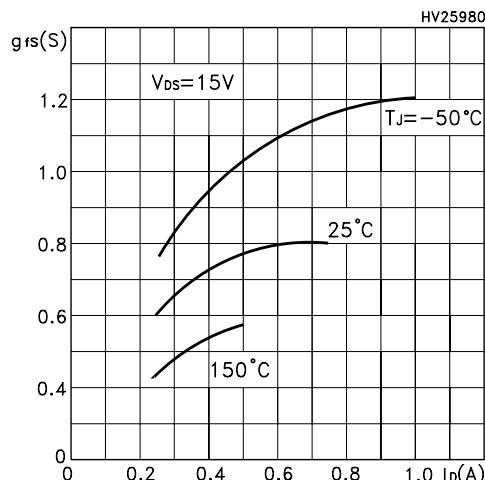


Figure 11: Gate Charge vs Gate-source Voltage

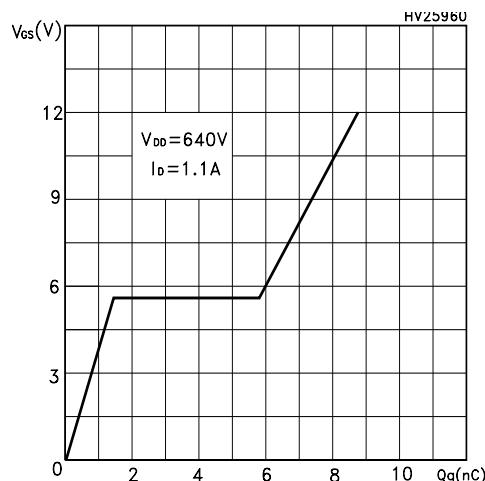


Figure 12: Transfer Characteristics

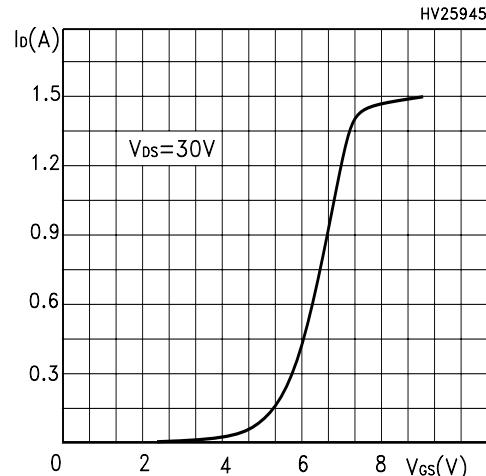


Figure 13: Static Drain-source On Resistance

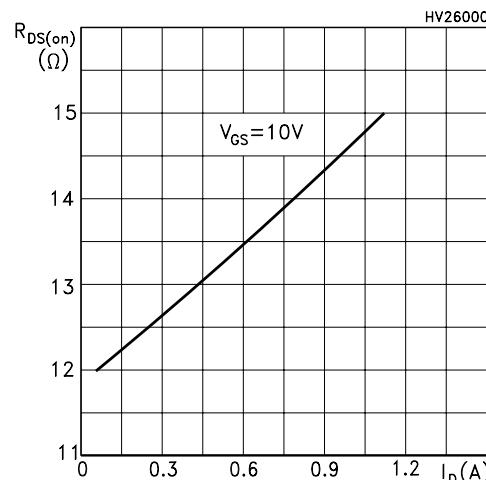
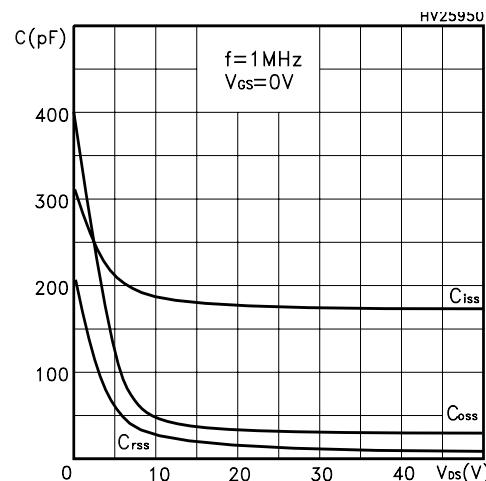


Figure 14: Capacitance Variations



STQ1NK80ZR-AP - STN1NK80Z - STD1NK80Z - STD1NK80Z-1

Figure 15: Normalized Gate Threshold Voltage vs Temperature

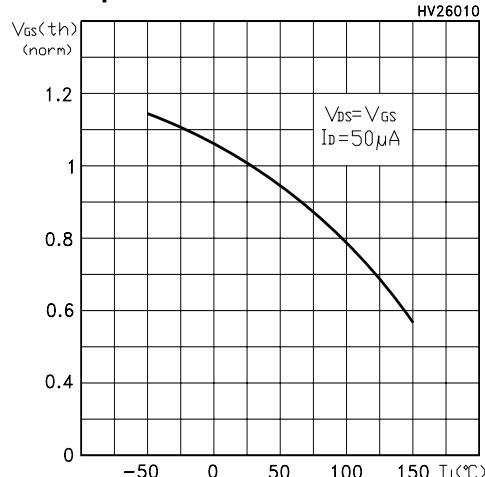


Figure 16: Source-Drain Diode Forward Characteristics

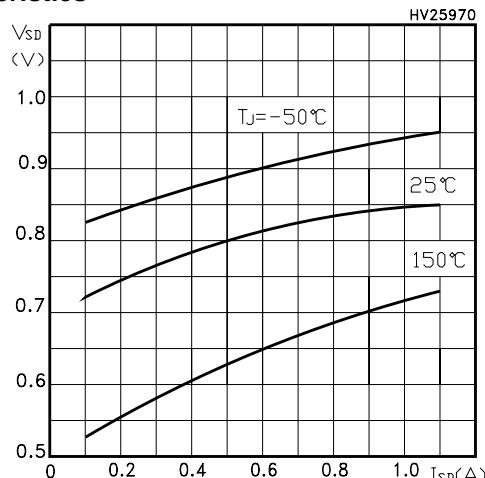


Figure 17: Avalanche Energy vs Starting Tj

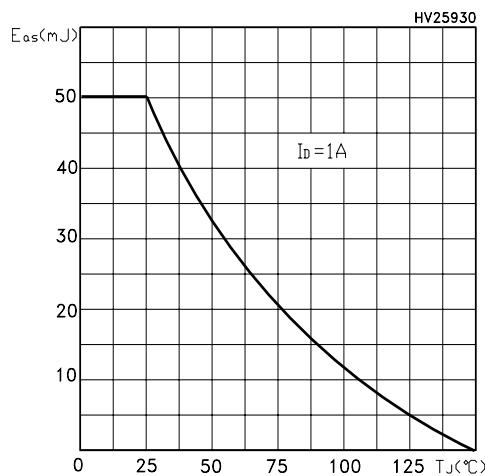


Figure 18: Normalized On Resistance vs Temperature

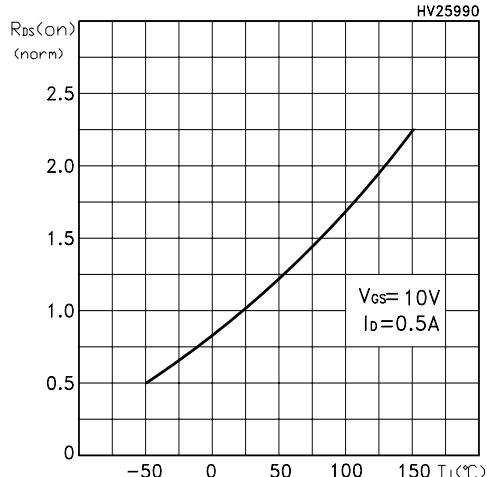
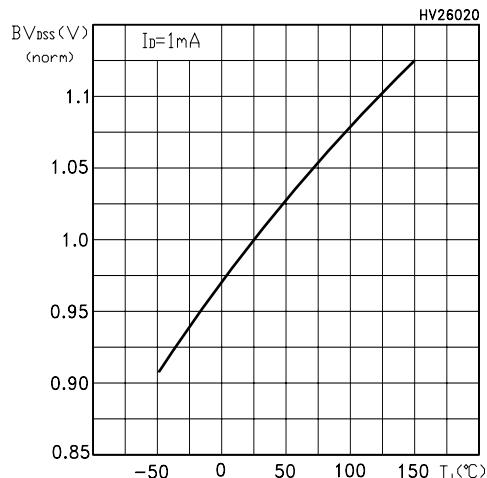


Figure 19: Normalized BVdss vs Temperature



STQ1NK80ZR-AP - STN1NK80Z - STD1NK80Z - STD1NK80Z-1

Figure 20: Unclamped Inductive Load Test Circuit

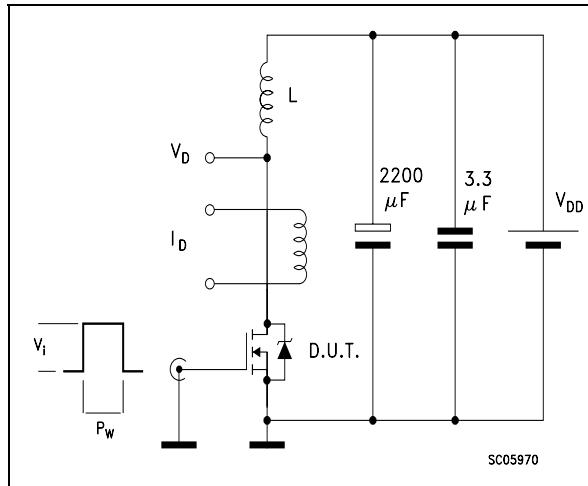


Figure 21: Switching Times Test Circuit For Resistive Load

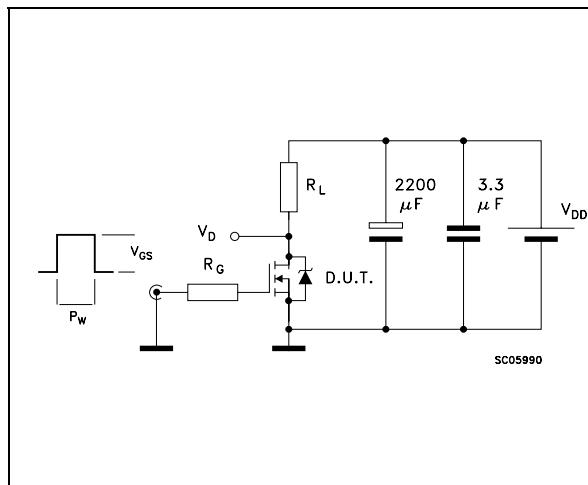


Figure 22: Test Circuit For Inductive Load Switching and Diode Recovery Times

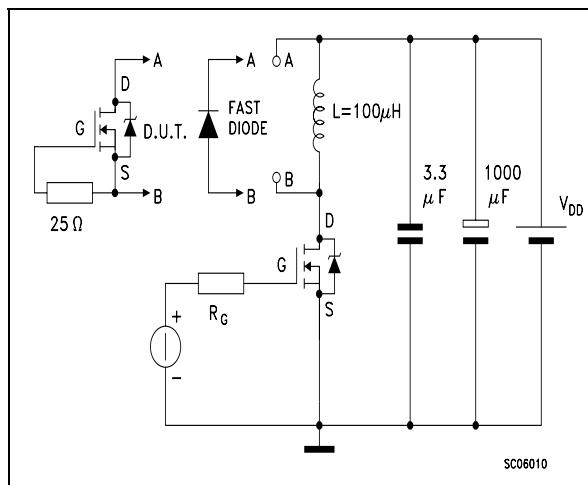


Figure 23: Unclamped Inductive Wafeform

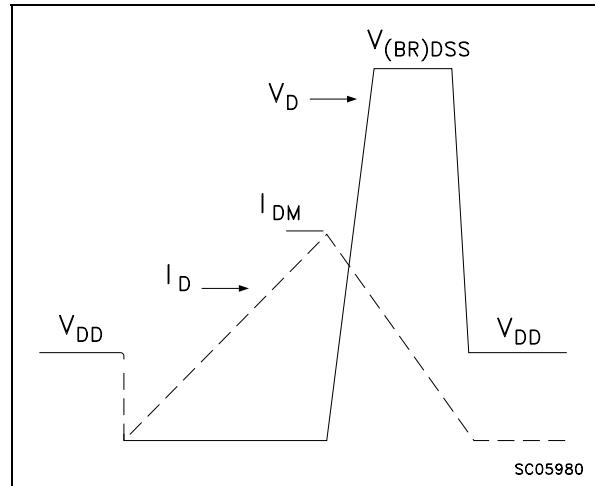
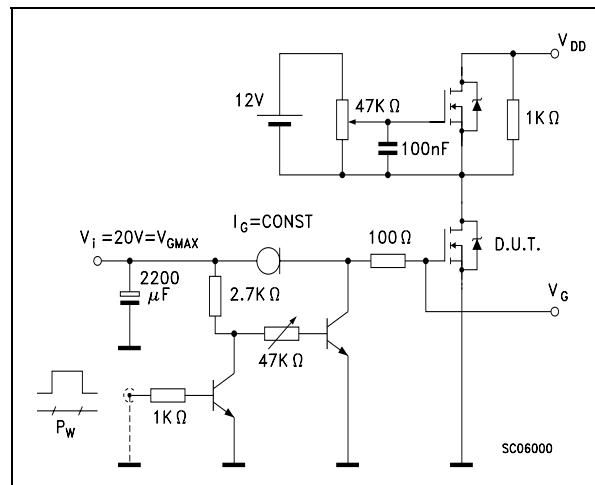


Figure 24: Gate Charge Test Circuit

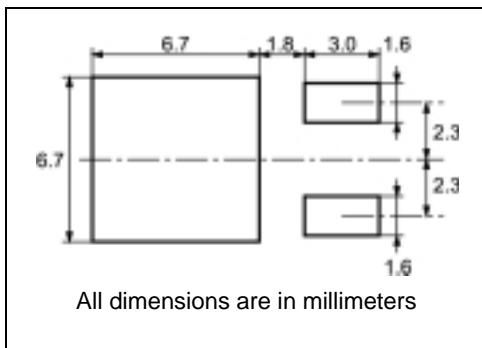


STQ1NK80ZR-AP - STN1NK80Z - STD1NK80Z - STD1NK80Z-1

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

STQ1NK80ZR-AP - STN1NK80Z - STD1NK80Z - STD1NK80Z-1

DPAK FOOTPRINT



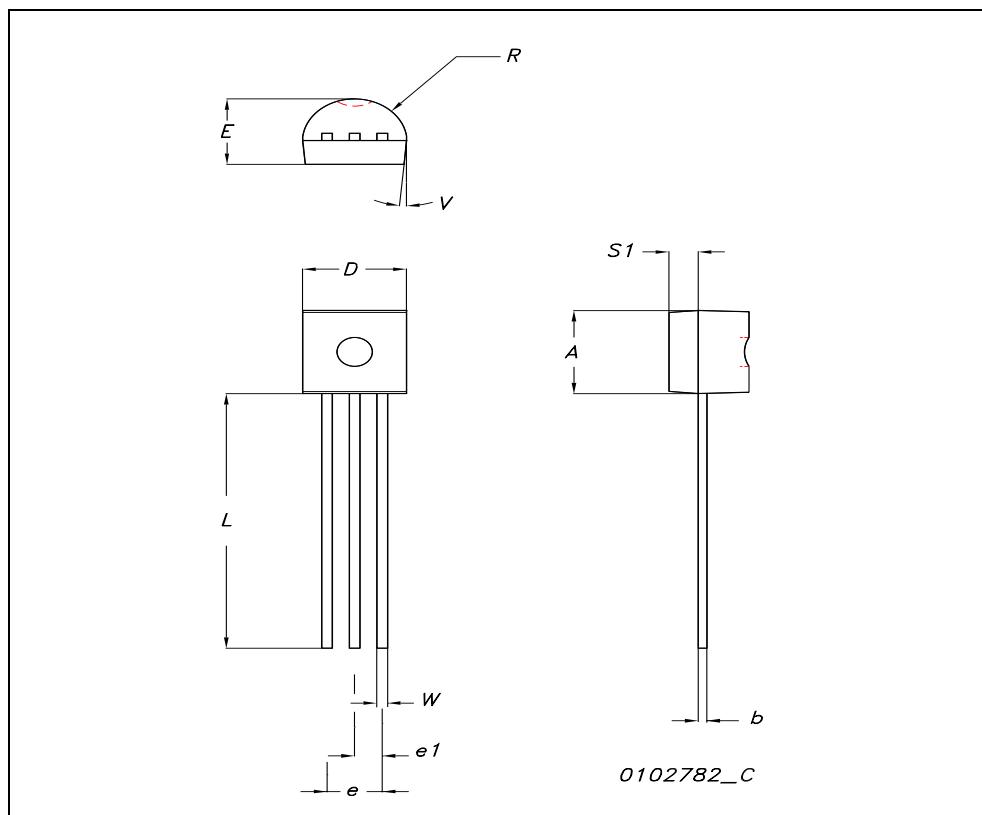
TAPE AND REEL SHIPMENT

<p>REEL MECHANICAL DATA</p> <table border="1" style="margin-top: 10px; border-collapse: collapse;"> <thead> <tr> <th rowspan="2">DIM.</th><th colspan="2">mm</th><th colspan="2">inch</th></tr> <tr> <th>MIN.</th><th>MAX.</th><th>MIN.</th><th>MAX.</th></tr> </thead> <tbody> <tr> <td>A</td><td>330</td><td></td><td>12.992</td><td></td></tr> <tr> <td>B</td><td>1.5</td><td></td><td>0.059</td><td></td></tr> <tr> <td>C</td><td>12.8</td><td>13.2</td><td>0.504</td><td>0.520</td></tr> <tr> <td>D</td><td>20.2</td><td></td><td>0.795</td><td></td></tr> <tr> <td>G</td><td>16.4</td><td>18.4</td><td>0.645</td><td>0.724</td></tr> <tr> <td>N</td><td>50</td><td></td><td>1.968</td><td></td></tr> <tr> <td>T</td><td>22.4</td><td></td><td>0.881</td><td></td></tr> </tbody> </table> <p>TAPE MECHANICAL DATA</p> <table border="1" style="margin-top: 10px; border-collapse: collapse;"> <thead> <tr> <th rowspan="2">DIM.</th><th colspan="2">mm</th><th colspan="2">inch</th></tr> <tr> <th>MIN.</th><th>MAX.</th><th>MIN.</th><th>MAX.</th></tr> </thead> <tbody> <tr> <td>A0</td><td>6.8</td><td>7</td><td>0.267</td><td>0.275</td></tr> <tr> <td>B0</td><td>10.4</td><td>10.6</td><td>0.409</td><td>0.417</td></tr> <tr> <td>B1</td><td></td><td>12.1</td><td></td><td>0.476</td></tr> <tr> <td>D</td><td>1.5</td><td>1.6</td><td>0.059</td><td>0.063</td></tr> <tr> <td>D1</td><td>1.5</td><td></td><td>0.059</td><td></td></tr> <tr> <td>E</td><td>1.65</td><td>1.85</td><td>0.065</td><td>0.073</td></tr> <tr> <td>F</td><td>7.4</td><td>7.6</td><td>0.291</td><td>0.299</td></tr> <tr> <td>K0</td><td>2.55</td><td>2.75</td><td>0.100</td><td>0.108</td></tr> <tr> <td>P0</td><td>3.9</td><td>4.1</td><td>0.153</td><td>0.161</td></tr> <tr> <td>P1</td><td>7.9</td><td>8.1</td><td>0.311</td><td>0.319</td></tr> <tr> <td>P2</td><td>1.9</td><td>2.1</td><td>0.075</td><td>0.082</td></tr> <tr> <td>R</td><td>40</td><td></td><td>1.574</td><td></td></tr> <tr> <td>W</td><td>15.7</td><td>16.3</td><td>0.618</td><td>0.641</td></tr> </tbody> </table> <p>BASE QTY BULK QTY</p> <table border="1" style="margin-top: 10px; border-collapse: collapse;"> <tr> <td>2500</td> <td>2500</td> </tr> </table>	DIM.	mm		inch		MIN.	MAX.	MIN.	MAX.	A	330		12.992		B	1.5		0.059		C	12.8	13.2	0.504	0.520	D	20.2		0.795		G	16.4	18.4	0.645	0.724	N	50		1.968		T	22.4		0.881		DIM.	mm		inch		MIN.	MAX.	MIN.	MAX.	A0	6.8	7	0.267	0.275	B0	10.4	10.6	0.409	0.417	B1		12.1		0.476	D	1.5	1.6	0.059	0.063	D1	1.5		0.059		E	1.65	1.85	0.065	0.073	F	7.4	7.6	0.291	0.299	K0	2.55	2.75	0.100	0.108	P0	3.9	4.1	0.153	0.161	P1	7.9	8.1	0.311	0.319	P2	1.9	2.1	0.075	0.082	R	40		1.574		W	15.7	16.3	0.618	0.641	2500	2500
DIM.		mm		inch																																																																																																																				
	MIN.	MAX.	MIN.	MAX.																																																																																																																				
A	330		12.992																																																																																																																					
B	1.5		0.059																																																																																																																					
C	12.8	13.2	0.504	0.520																																																																																																																				
D	20.2		0.795																																																																																																																					
G	16.4	18.4	0.645	0.724																																																																																																																				
N	50		1.968																																																																																																																					
T	22.4		0.881																																																																																																																					
DIM.	mm		inch																																																																																																																					
	MIN.	MAX.	MIN.	MAX.																																																																																																																				
A0	6.8	7	0.267	0.275																																																																																																																				
B0	10.4	10.6	0.409	0.417																																																																																																																				
B1		12.1		0.476																																																																																																																				
D	1.5	1.6	0.059	0.063																																																																																																																				
D1	1.5		0.059																																																																																																																					
E	1.65	1.85	0.065	0.073																																																																																																																				
F	7.4	7.6	0.291	0.299																																																																																																																				
K0	2.55	2.75	0.100	0.108																																																																																																																				
P0	3.9	4.1	0.153	0.161																																																																																																																				
P1	7.9	8.1	0.311	0.319																																																																																																																				
P2	1.9	2.1	0.075	0.082																																																																																																																				
R	40		1.574																																																																																																																					
W	15.7	16.3	0.618	0.641																																																																																																																				
2500	2500																																																																																																																							

STQ1NK80ZR-AP - STN1NK80Z - STD1NK80Z - STD1NK80Z-1

TO-92 MECHANICAL DATA

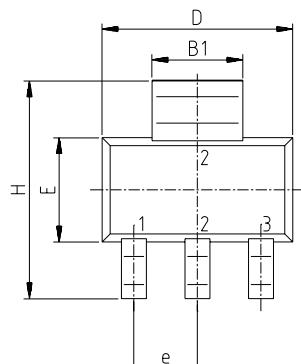
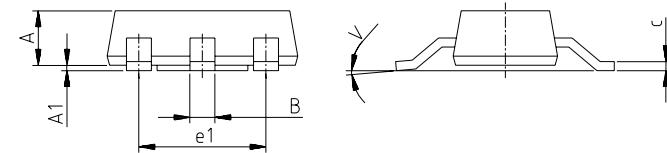
DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.32		4.95	0.170		0.194
b	0.36		0.51	0.014		0.020
D	4.45		4.95	0.175		0.194
E	3.30		3.94	0.130		0.155
e	2.41		2.67	0.094		0.105
e1	1.14		1.40	0.044		0.055
L	12.70		15.49	0.50		0.610
R	2.16		2.41	0.085		0.094
S1	0.92		1.52	0.036		0.060
W	0.41		0.56	0.016		0.022
V		5°			5°	



STQ1NK80ZR-AP - STN1NK80Z - STD1NK80Z - STD1NK80Z-1

SOT-223 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.80			0.071
B	0.60	0.70	0.80	0.024	0.027	0.031
B1	2.90	3.00	3.10	0.114	0.118	0.122
c	0.24	0.26	0.32	0.009	0.010	0.013
D	6.30	6.50	6.70	0.248	0.256	0.264
e		2.30			0.090	
e1		4.60			0.181	
E	3.30	3.50	3.70	0.130	0.138	0.146
H	6.70	7.00	7.30	0.264	0.276	0.287
V			10°			10°
A1		0.02				

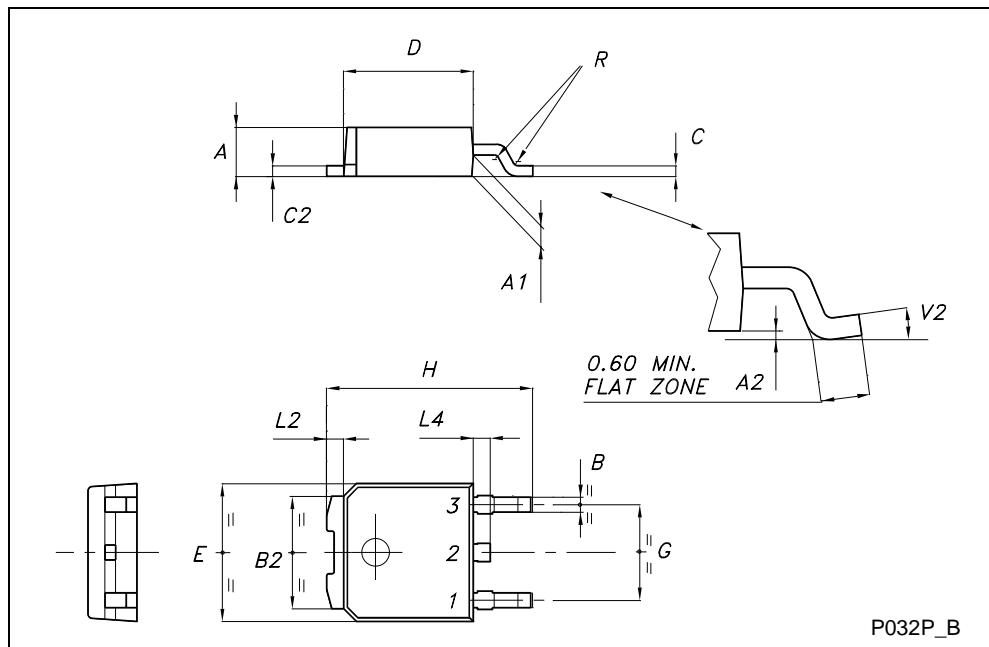


P008B

STQ1NK80ZR-AP - STN1NK80Z - STD1NK80Z - STD1NK80Z-1

TO-252 (DPAK) MECHANICAL DATA

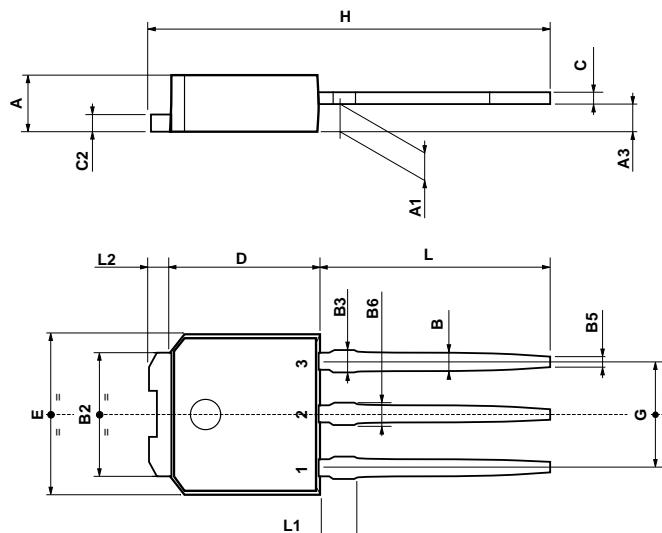
DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	2.20		2.40	0.087		0.094
A1	0.90		1.10	0.035		0.043
A2	0.03		0.23	0.001		0.009
B	0.64		0.90	0.025		0.035
B2	5.20		5.40	0.204		0.213
C	0.45		0.60	0.018		0.024
C2	0.48		0.60	0.019		0.024
D	6.00		6.20	0.236		0.244
E	6.40		6.60	0.252		0.260
G	4.40		4.60	0.173		0.181
H	9.35		10.10	0.368		0.398
L2		0.8			0.031	
L4	0.60		1.00	0.024		0.039
V2	0°		8°	0°		0°



STQ1NK80ZR-AP - STN1NK80Z - STD1NK80Z - STD1NK80Z-1

TO-251 (IPAK) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	2.2		2.4	0.086		0.094
A1	0.9		1.1	0.035		0.043
A3	0.7		1.3	0.027		0.051
B	0.64		0.9	0.025		0.031
B2	5.2		5.4	0.204		0.212
B3			0.85			0.033
B5		0.3			0.012	
B6			0.95			0.037
C	0.45		0.6	0.017		0.023
C2	0.48		0.6	0.019		0.023
D	6		6.2	0.236		0.244
E	6.4		6.6	0.252		0.260
G	4.4		4.6	0.173		0.181
H	15.9		16.3	0.626		0.641
L	9		9.4	0.354		0.370
L1	0.8		1.2	0.031		0.047
L2		0.8	1		0.031	0.039



0068771-E

STQ1NK80ZR-AP - STN1NK80Z - STD1NK80Z - STD1NK80Z-1

Table 10: Revision History

Date	Revision	Description of Changes
08-Jun-2005	1	First Release
06-Sep-2005	2	Inserted Ecopack indication

STQ1NK80ZR-AP - STN1NK80Z - STD1NK80Z - STD1NK80Z-1

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics

All other names are the property of their respective owners

© 2005 STMicroelectronics - All Rights Reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -
Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America